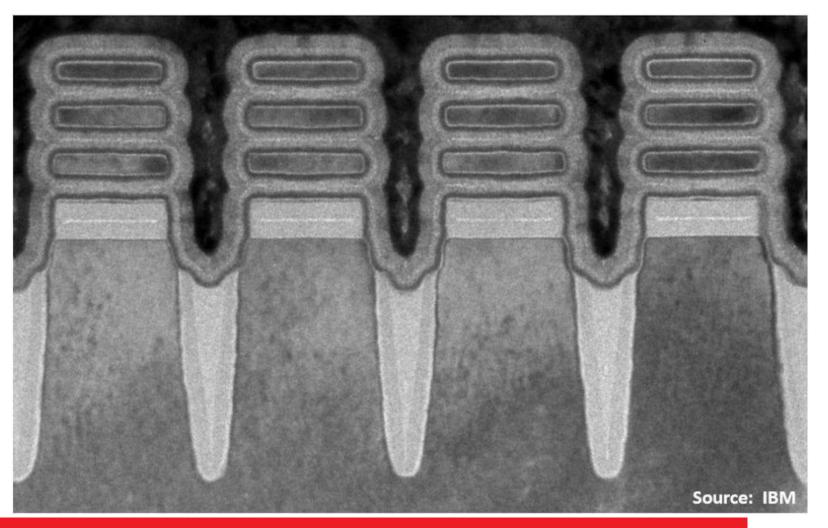
# Module 2 Unit 2: Dielectrics

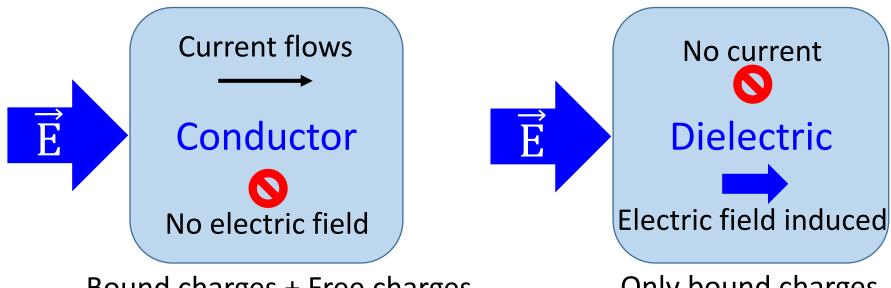
Dr. Suren Patwardhan



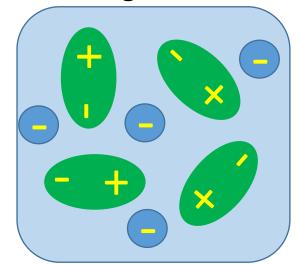
#### Contents

- 1. Classification of materials based on dielectric property
- 2. Dielectric parameters P, D, E, k  $\epsilon$  etc.
- 3. Type of polarization
- 4. Expression for electronic polarizability
- 5. Clausius-Mossotti equation
- 6. Frequency dependence of polarization
- 7. Dielectric strength
- 8. Ferroelectricity

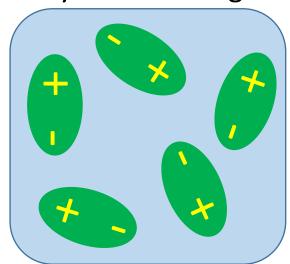
#### Difference between Conductor and Dielectric



Bound charges + Free charges







#### Classification of Materials Based on Electric Polarization

#### Application of Electric Field

#### Conductors

- Free charges respond
- constitute current
- No electric field is set
- Example: Cu
- Use: Electric Interconnections

#### **Insulators**

- Bound charges respond
- No current flows
- Electric field is set up
- Example: Glass, Ceramic

#### Conventional

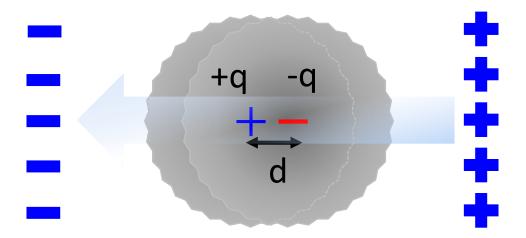
- Weak response
- No polarization\*
- Example: PVC
- Use: Electrical isolation

#### **Dielectrics**

- Strong response
- Material is polarized
- Example: Mica
- Use: Capacitors

\*static charge and heat energy conversion takes place

1) Electronic/Atomic (all materials)

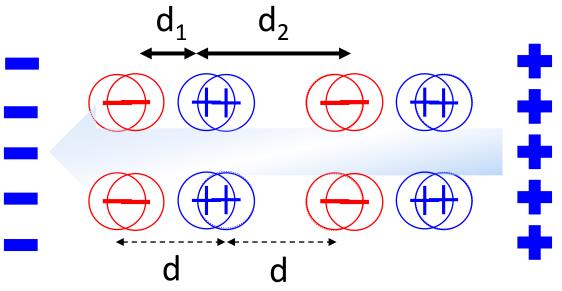


Induced electric dipole moment:  $\vec{\mu} = qd \hat{r}$ 

Polarization: 
$$\vec{P} = \sum_{i=1}^{n} \vec{\mu}_{i} \Rightarrow \vec{P}_{e} = 4\pi\epsilon_{0}NR^{3}\vec{E}$$

2) Ionic (solids possessing ionic bonds e.g. NaCl)

net dipole moment:  $\vec{\mu}=\mu_2-\mu_1=Q(d_2-d_1)\hat{r}$  After applying field



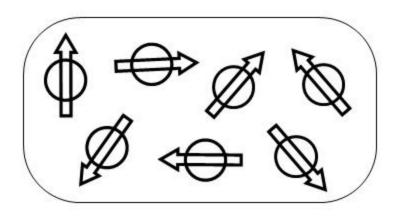
Polarization:

$$\vec{P_i} = \frac{Ne^2}{\omega_0^2} \left[ \frac{1}{M} + \frac{1}{m} \right] \vec{E}$$

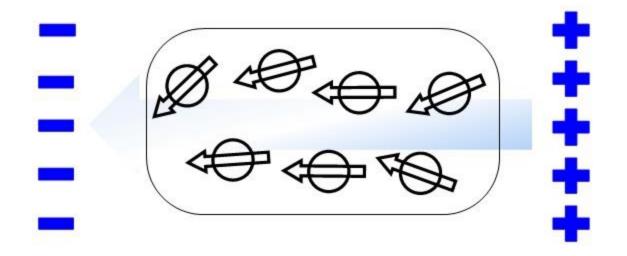
Before applying field

net polarization:  $\vec{p} = 0$ 

Orientational or Dipolar (polar fluids e.g. liquid crystals)

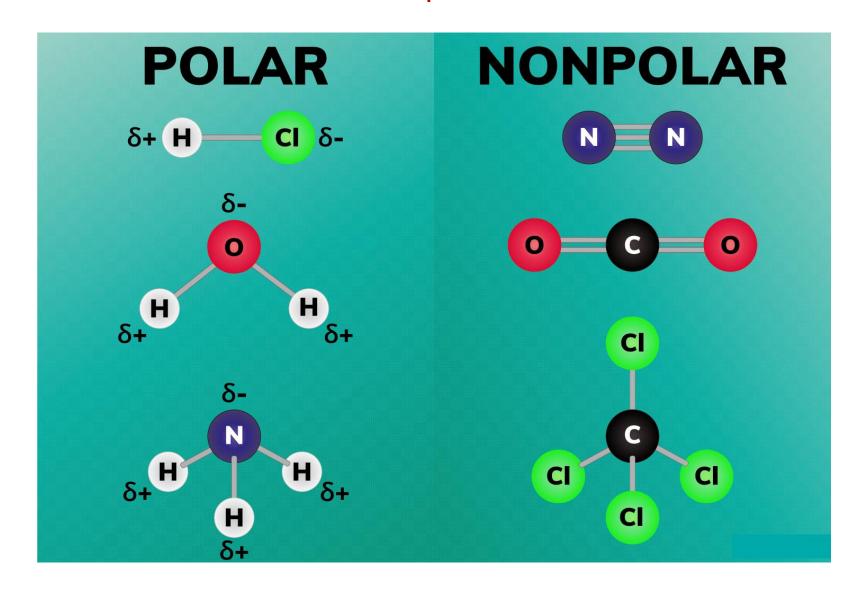


Orientational or Dipolar (polar fluids e.g. liquid crystals)

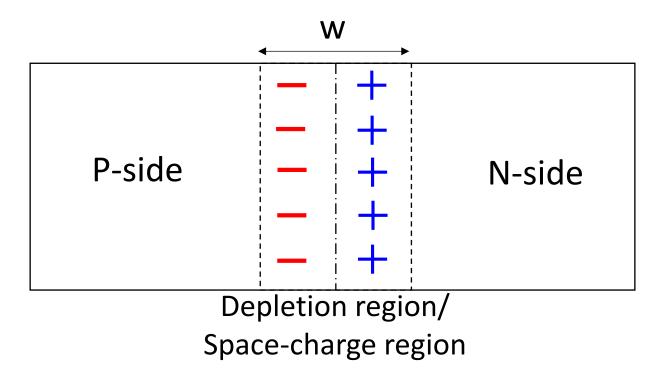


Polarization: 
$$\vec{P} = \sum_{i=1}^{n} \vec{\mu}_i = \vec{P}_o = \frac{N\mu^2\vec{E}}{3kT}$$

## Polar and Non-polar Molecules



Space-charge or Interfacial (e.g. p-n junction, metal-semiconductor junction, Metal Oxide-Semiconductor junction)



Polarization:  $\vec{P} = qN_DAw\hat{r}$ 

# Expressions for Dielectric Parameters

Dielectric Quantity	Expression
Electric field $(\overrightarrow{E})$	$\vec{E} = -\vec{\nabla}V = -\frac{dV}{dx}$ (in 1 – D) (for calculations, $E = \frac{V}{d}$ )
Electric Displacement ( $\overrightarrow{D}$ )	$\vec{D} = \epsilon_0 \vec{E},$ $\vec{D} = \epsilon_0 \vec{E} + \vec{P}$
Polarization ( $\overrightarrow{P}$ ):	$\vec{P} = \epsilon_0 \chi_e \vec{E} = \epsilon_0 (k - 1) \vec{E}$ $\vec{P} = \frac{\sum \vec{\mu}_j}{V} = \alpha N \vec{E}$
Capacitance (C):	$C = \frac{k\epsilon_0 A}{d}$
Electric dipole moment $(\vec{\mu})$ :	$\vec{\mu} = Qd \hat{r}$

# Polarizability and Dielectric Constant

Dielectric Quantity	Expression	
Polarizability ( $\alpha$ ):	$\vec{\mu} = \alpha \vec{E}$	
Electronic polarizability:	$\alpha_{\rm e} = 4\pi\epsilon_0 R^3$	

$$\alpha = \frac{\epsilon_0(k-1)}{N}$$
 gases

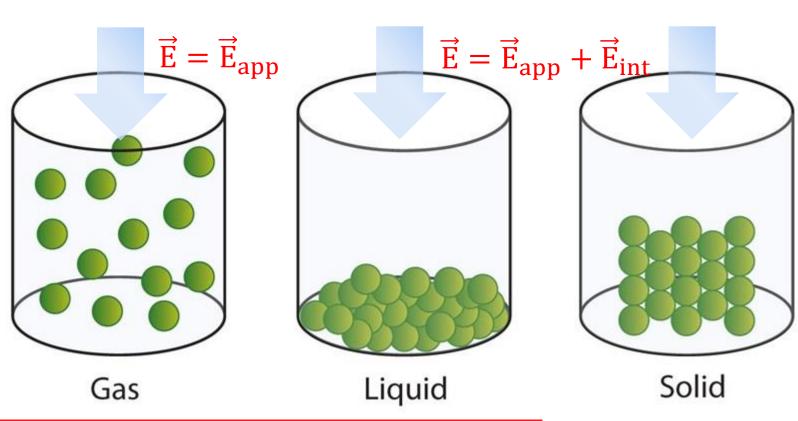
$$\alpha = \frac{3\epsilon_0}{N}\frac{(k-1)}{(k+2)}$$
 solids and liquids (Claussius-Mosotti Equation)

## Internal Fields in Solids and Liquids

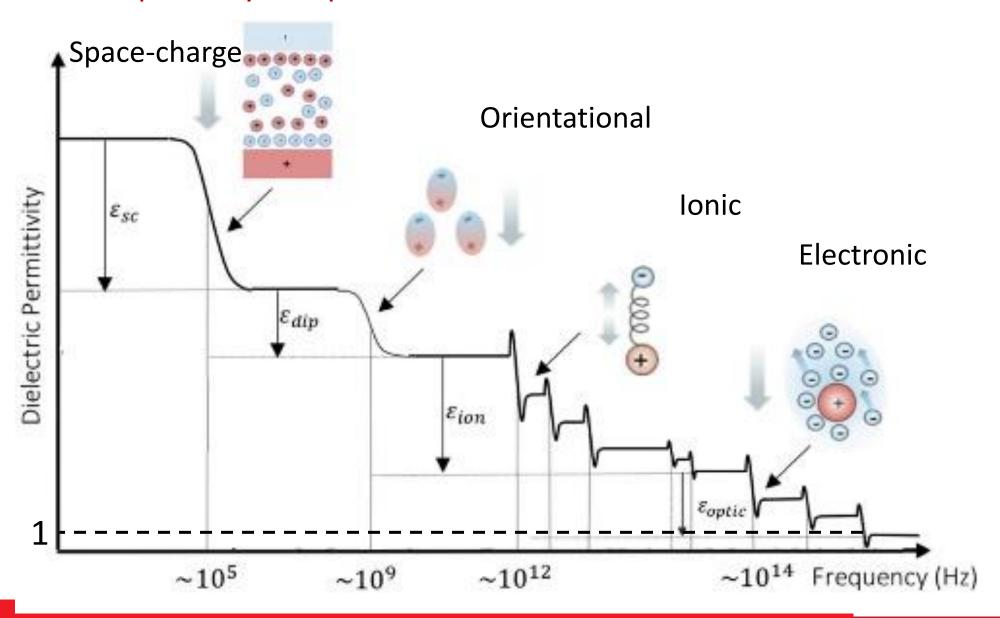
- In gases, atoms/molecules are far away from each other
- In solids and liquids, atoms/molecules are in close proximity
- Each atom/molecule is influenced by polarization of neighbours

Internal field:  $\vec{E}_i = \frac{\gamma \vec{P}}{\epsilon_0}$ ;

y: Internal field constant



## Frequency Dependence Of Dielectric "Constant"



## Frequency Dependence Of Polarization

Total polarization is given by

$$P = Electronic + Ionic + Orientational = N(\alpha_e + \alpha_i + \alpha_o)E$$

Frequency regime	Range	Type of polarization present	
Quasi-DC	1-10 Hz	All of electronic, ionic, orientational and Space charge	
Audio	KHz – MHz (10 <sup>3</sup> -10 <sup>6</sup> )	All electronic, ionic and orientational except space charge	
RF to Microwave	MHz – THz (10 <sup>6</sup> -10 <sup>12</sup> )	Only electronic and ionic	
IR to Optical	THz – PHz (10 <sup>12</sup> -10 <sup>15</sup> )	Only electronic	
UV	> PHz (10 <sup>15</sup> )	None	

# Dielectric Strength

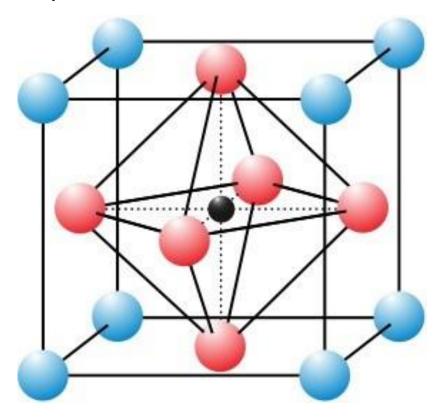
Insulating material	Dielectric constant or relative permittivity	Dielectric Stren	gth in
Air Asbestos* Bakelite Epoxy	1.0006 2 5 3.3	3.2 2 15 20	
Glass Marble* Mica Micanite Mineral Oil Mylar Nylon Paper Paraffin wax Polyethylene Polyurethane Porcelain PVC Quartz	5-12 7 4-8 4-5-6 2.2 3 4.1 1.8-2.6 1.7-2.3 2.3 3.6 5-6.7 3.7 4.5-4.7	12-100 2 20-200 25-35 10 400 16 18 30 40 35 15 50 8	Max voltage a dielectric material can withstand before electric discharge
Rubber Teflon	2.5-4	12-20 20	

#### Dielectric Relaxation Time and Relaxation Frequency

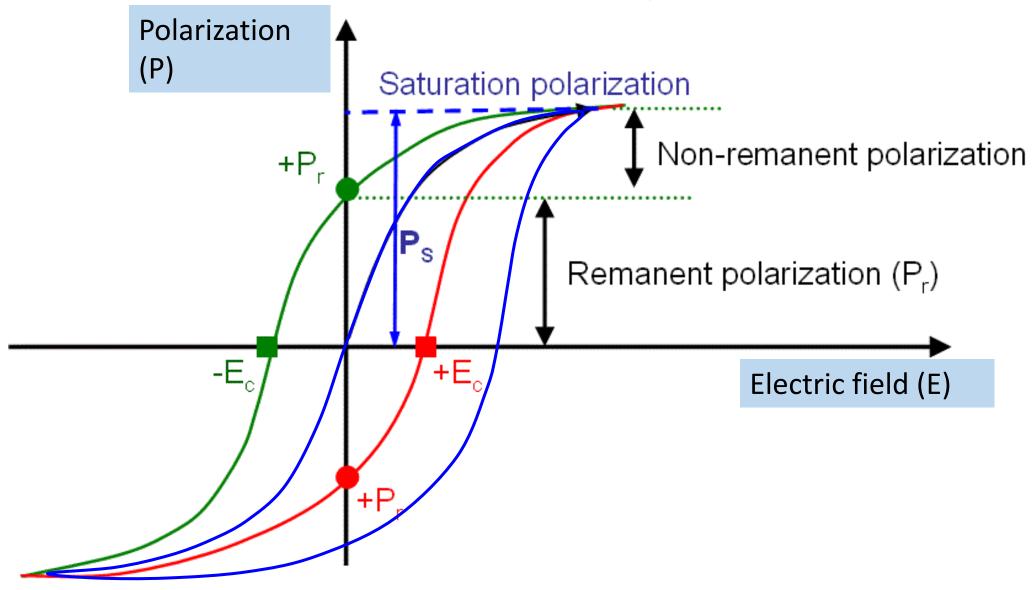
- Dielectric relaxation time  $(\tau_r)$ :
  - Average time taken by the dipole to orient in the field direction
- Dielectric frequency (f<sub>r</sub>):
   Reciprocal of relaxation time
- If f<sub>electric field</sub> > f<sub>r</sub> dipoles cannot orient themselves along the field
- Condition for alignment of dipoles:  $\tau_r \leq \frac{T_{electric field}}{2}$

#### Ferroelectricity

- Spontaneous polarization shown by certain materials e.g. BaTiO<sub>3</sub>, PbTiO<sub>3</sub>
- Very high permittivity: 1000 to 10000
- Non-linear dependence of polarization on electric field

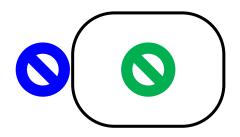


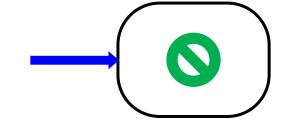
## Ferroelectricity



## Hysteresis Effect of a Ferroelectric Material

Means: Some electric field is "consumed" Hysteresis is "non-conservative" process





Initial state was:

After one cycle:

Electric field = 0

Electric field ≠ 0

Polarization = 0

Polarization = 0

Electric field increases
Polarization increases

Electric field increases further Polarization saturates

Electric field decreases
Polarization decreases

Electric field becomes zero Polarization retains

Electric field reversed
Polarization becomes zero

## Applications of Dielectric Materials

- Capacitors (paper, ceramic, plastic, vacuum)
- Heating appliances (mica)
- Power line transmission (ceramic discs)
- High-tension Transformers (Dielectric liquids)
- Displays (Liquid crystals)
- Sensors (MEMs)
- USB/Flash memory (floating gate MOSFET)
- Semiconductor Chips (conventional MOSFET, FinFETs, GAAFETs, MBCFETs)